

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application:

Doo Hyeb YOUN et al

GRP ART UNIT: 2814

Serial No:

10/576,579

Ex.. Pham, Long

Filed: April 20, 2006

For:

METAL INSULATIOR TRANSITION SWITCHING DEVICE AND METHOD

FOR MAUFACTURING THE SAME

Certification under 37 C.F.R. §1.8(a)

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being deposited with The United States Postal Service with sufficient postage as first class mail in an envelope addressed to The Commissioner for Patents. P.O. Box 1450 Alexandria, VA 22313-1450 on July 3

<u>Kasea</u> Januszewski Kasia Januszewski

Commissioner for Patents P.O. Box 1450 Alexandria VA 22313-1450

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT BEFORE MAILING OF A FINAL ACTION OR THE NOTICE OF ALLOWANCE

The information disclosure statement submitted herewith is being filed before the mailing date of either a final action under §1.113, or a notice of allowance under §1.311, 37 CFR 1.97(c). The Commissioner is authorized to charge \$180.00 to cover the fee set forth in §1.17(p). The Commissioner is also authorized to charge any other required fees to our Deposit Account No. 12-0400.

W/ William Park, Reg. No. 55,523

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224 South Michigan Avenue

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JUL 0 5 2007

KET: CU-4794

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INFORMATION DISCLOSURE STATEMENT (IDS)

Applicant submits herewith patents, publications or other information of which the applicant is aware, which may be material to the examination of this application and in respect of which there may be a duty to disclose under 37 CFR 1.56.

No paper copies of the U.S. patent references identified in this IDS, if any, are submitted herewith as they are no longer required by the USPTO rules. Only the copies of foreign patent and/or other relevant publication references are submitted herewith.

The filing of this information disclosure statement shall not be construed as a representation that a search has been made (37 CFR 1.97(g)), an admission that the information cited is, or is considered to be, material to patentability or that no other material information exists.

The filing of this information disclosure statement shall not be construed as an admission against interest in any manner. Notice of January 9, 1992, 1135 O.G. 13-25, at 25.

The references submitted herein are listed on PTO-1449 form (modified) enclosed herewith. A copy of each reference listed is being furnished except any duplicate or cumulative patents or publications specified otherwise.

A translation of any foreign language reference, if any, is indicated in PTO-1449 form and being submitted herein if it is readily available. Otherwise it should be construed that such translation is not readily available.

The Statement is made on the basis of the information:

- <u>X</u> supplied by an individual associated with the filing and prosecution of this application (37 CFR 1.56(c));
- X cited in a corresponding PCT, EPO, and/or foreign application, if any.

<u>2007, 2 July 2</u>

Hank

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224 South Michigan Avenue

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Respectfully submitted,

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JUL 0 5 2007
Form PTO-1449 (Modified)

FORM PTO-1449	ATTY. DOCKET NO.	SERIAL NO.		
	CU 4794	10/576,579		
INFORMATION DISCLOSURE	Applicant			
STATEMENT BY APPLICANT	Doo Hyeb YOUN et al			
	FILING DATE	GROUP		
(37 CFR 1.98(b))	April 20, 2006	2814		

U.S. PATENT OR PUBLISHED U.S. PATENT APPLICATION DOCUMENTS

EXAMINER INITIAL	PATENT DOCUMENT	ISSUE/PUB DATE	PATENTEE	CLASS	SUB- CLASS	FILING DATE
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FOREIGN PATENT OR PUBLISHED FOREIGN PATENT APPLICATION

TOTAL CONTINUE OF				•			
EXAMINER INITIAL	DOCUMENT NUMBER	PUBL. DATE	COUNTRY OR PATENT OFFICE	CLASS	SUB- CLASS	TRANSL YES	ATION NO
	WO9534504	12/21/95	PCT				
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Examiner	DATE CONSIDERED		
J			

Examiner: Initial citation considered. Draw line through citation if not In conformance and not considered. Include copy of this form with next communication to applicant.

(Form PTO-1449) ブーューンのク